Supporting Information for

# **Organic Solvent Assisted Intercalation and Collection for**

# Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> MXene with Controllable Sizes and Improved Yield

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## **Supplementary Tables and Figures**



**Fig. S1** Digital photographs of (a) supernatant and sediment after adding DCM and centrifugation at speed of 2,000 rpm (Step 6). (b) the synthesized  $O-Ti_3C_2T_x$  solution placed for one week at room temperature (left) and the diluted solution showing Tyndall

scattering effect (right). (c) the O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> film with diameter 40 mm made by vacuumassisted filtration, indicating the good film-forming ability. (d) the Swagelok threeelectrode setup used in electrochemical measurements. (e) Schematic representation of a Swagelok cell. The glassy carbon electrodes were used as current collectors for both the working and the counter electrodes. The prepared  $Ti_3C_2T_x$  films were punched to the desired size and were directly used as the working electrode without addition of any binder. The freestanding overcapactive activated carbon electrode was used as the counter electrode. The Ag/AgCl electrode in 1 M KCl was used as the reference electrode. Two pieces of Celgard paper (3501) were used as the separator between the working electrode and the counter electrode. The deaerated 3 M H<sub>2</sub>SO<sub>4</sub> was used as the electrolyte.



**Fig. S**2 SEM images of (a)  $S-Ti_3C_2T_x-1$ , (b)  $S-Ti_3C_2T_x-6$  flakes through Route II, and (c)  $O-Ti_3C_2T_x-1$ , (d)  $O-Ti_3C_2T_x-6$  flakes through Route III



Fig. S3 TEM images of (a) S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-2, (b) S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-3, (c) S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-4, (d) S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-5 flakes



Fig. S4 TEM images of (a) O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-2, (b) O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-3, (c) O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-4, (d) O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-5 flakes



Fig. S5 High-resolution TEM image of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>

а	120 100 100	40 130 200 200	26 36 36	<sup>20</sup> 0-Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub> -3	0-TisCaTx-4	0-Ti <sub>3</sub> C <sub>2</sub> T x-5	8 0-Ti <sub>2</sub> C <sub>2</sub> T <sub>x</sub> -6
Flake-area distribution	δ <sub>m</sub> Avg. 0.16 μm <sup>2</sup> Ares (um <sup>2</sup> )	<sup>5</sup> <sub>20</sub> <sup>10</sup> <sup>10</sup> <sup>10</sup> <sup>10</sup> <sup>10</sup> <sup>10</sup> <sup>10</sup> <sup>10</sup>	500 Avg. 1.18 μm <sup>2</sup> 60 1 2 3 4 5 0 7 4 4 10 Area (μm <sup>2</sup> )	Avg. 1.79 μm <sup>2</sup>	δ Avg. 2.40 μm <sup>2</sup> δ 4 1 2 3 4 5 6 7 6 4 10 Area (μm <sup>2</sup> )	<sup>n</sup> <sup>4</sup> <sup>1</sup> <sup>2</sup> <sup>3</sup> <sup>4</sup> <sup>4</sup> <sup>4</sup> <sup>5</sup> <sup>4</sup> <sup>5</sup> <sup>4</sup> <sup>6</sup> <sup>7</sup> <sup>7</sup> <sup>8</sup> <sup>6</sup> <sup>7</sup> <sup>8</sup> <sup>6</sup> <sup>7</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup> <sup>8</sup>	5 π Avg. 4.60 μm <sup>2</sup> 4 1 2 3 4 5 7 7 μ = 1 Area (μm <sup>2</sup> )
b Representative TEM images	Enteral suze=0.48 µm 30 <u>0 mm</u> 0.43 µm	Lateral str=1.12 pm	Laters size 1.75 Lm 5 <u>00 nm</u>	Lateral size=2.12 µm 5 <u>00 nm</u>	Lateral siza=2.16 µm 50 <u>0 n</u> m	Lateral size=2.79 _m . 50 <u>0 n</u> m	Annun 465 (m <sup>.</sup> Lateral eize-322 (m . 580-rim
Area [µm <sup>2</sup> ]	0.16±0.09	0.47±0.34	1.18±0.58	1.79±0.84	2.40±1.00	3.58±1.19	4.60±1.98
Lateral size [µm]	0.45±0.16	0.75±0.14	1.28±0.18	1.62±0.19	1.79±0.20	2.23±0.31	3.02±0.49
C Film sheet resistance maps						Provide a state of the state of	
Sheet resistance [Avg.] $[\Omega \text{ sq}^{+}]$	1.882040	1.302450	0.8849400	0.8018200	0.6690150	0.3276050	0.5765573
Film thickness [µm]	5	6	5	3	3	5	2
Conductivity [S cm <sup>-1</sup> ]	1062.7	1279.6	2260.0	4157.2	4982.4	6104.9	8672.2

**Fig. S6** S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> and O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> flakes size, structure, and conductivity. (a) Flake-area distribution diagrams, (b) Representative TEM images of  $Ti_3C_2T_x$  flakes. Blue lines

outline the area of  $Ti_3C_2T_x$  flakes, and white lines outline the lateral size of  $Ti_3C_2T_x$  flakes. TEM-derived area and lateral size distributions were determined by measuring the area and lateral size of 100 flakes. The average values of flakes area and lateral size list below. (c) Sheet resistance (Rs) maps of  $Ti_3C_2T_x$  films fabricated by vacuum filtration. The average values of Rs and corresponding film thickness (d) list below. The conductivity,  $\sigma$  (S cm<sup>-1</sup>), was calculated by  $\sigma=1/(Rs \times d)$ 



Fig. S7 TEM images for O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-1 to O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-6 flakes of gram-level preparation



Fig. S8 Energy-dispersive X-ray spectroscopy (EDS) spectra of (a)  $S-Ti_3C_2T_x$  and (b)  $O-Ti_3C_2T_x$ 

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Fig. S11 Galvanostatic charge-discharge (GCD) profiles of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-3



Fig. S12 CV profiles of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-1 to O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-6 film electrodes at scan rates from 2 mV s<sup>-1</sup> to 10 V s<sup>-1</sup>



Fig. S13 Volumetric capacitance of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-1 to O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>-6 film electrodes at different scan rates



Fig. S14 (a) CV profiles of S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>, (b) Gravimetric capacitance of S-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> film electrode at different scan rates

	Ti (at%)	C (at%)	O (at%)	F (at%)
S-Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	29.22	40.69	17.00	13.09
$O-Ti_3C_2T_x$	30.12	45.89	15.19	8.80

Table S1 Summary of atomic ratios of S-Ti\_3C\_2T\_x and O-Ti\_3C\_2T\_x

Cycle	m (g)	(g)	c (g mL <sup>-1</sup> )	m <sub>dis</sub> (g)	Total production (g)
1	$m_1 = 0.0547$				
	$m_2 = 0.0533$				
	$m_3 = 0.0534$	0.0536	0.01072	1.2864	
	$m_4 = 0.0533$				
	m5=0.0533				
	$m_1 = 0.0480$				
	$m_2 = 0.0479$				
2	$m_3 = 0.0477$	0.04788	0.009576	0.76608	
	$m_4 = 0.0480$				
	$m_5 = 0.0478$				4 62028
	$m_1 = 0.0276$				4.02320 Vield $- 46.20\%$
	$m_2 = 0.0268$		0.005516	1.54448	
3	$m_3 = 0.0281$	0.02758			
	$m_4 = 0.0276$				
	$m_5 = 0.0278$				
	$m_1 = 0.0230$				
4	$m_2 = 0.0230$				
	$m_3 = 0.0230$	0.02302	0.004604	0.82872	
	$m_4 = 0.0231$				
	m5=0.0230				
5	$m_1 = 0.0056$	0.00562	0.001124	0.1124	

Table S2 Yield calculation of gram-level preparation for O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>

	$m_2 = 0.0055$				
	$m_3 = 0.0056$				
	$m_4 = 0.0057$				
	$m_5 = 0.0057$				
	$m_1 = 0.0046$				
	$m_2 = 0.0044$				
6	$m_3=0.0044$	0.00456	0.000912	0.0912	
	$m_4 = 0.0046$				
	$m_5 = 0.0048$				

The volumes of dispersion in step 8 in each cycle were accurately measured which denoted as  $V_{\text{dis}}$ . Then, the dispersion of each cycle was extracted for five parts with 5 ml of each part. After freeze-drying, the O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> products of each part were weighted and denoted as  $m_1$  to  $m_5$ . The mass concentration of the dispersion can be calculated by the following equation:  $c = \frac{\overline{m}}{V}$ , where  $\overline{m}$  is the average mass of five parts, V is 5 ml. So far, the mass of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> products in dispersion of each cycle (denote as  $m_{\text{dis}}$ ) can be calculated by the following equation:  $m_{dis} = cV_{dis}$ . The yield of gram-level preparation was calculated by total mass of O-Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> products in the dispersion dividing by the mass of Ti<sub>3</sub>AlC<sub>2</sub> powders (10 g).

Table S3 A brief summary of capacitive performance of pristine  $Ti_3C_2T_x$ 

Materials	Synthesis methods	Lateral Size	Electrolyte	Gravimetric capacitance	Rate performance ª	Refs.
S-pristine Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/HF	150 nm	$3M H_2 SO_4$	~300 F g <sup>-1</sup> @ 5 mV s <sup>-1</sup>	~70% at 1000mV s <sup>-1</sup>	[S1]
L-pristine Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/HF	1.28 μm	$3M H_2 SO_4$	~290 F g <sup>-1</sup> @ 5 mV s <sup>-1</sup>	~20.7% at 1000 mV s <sup>-1</sup>	[S1]
Pristine Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/LiF	< 1 µm	$3M H_2 SO_4$	348 F g <sup>-1</sup> @ 5 mV s <sup>-1</sup>	~30.2% at 1000 mV s <sup>-1</sup>	[S2]
Pure Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/LiF	/	$3M H_2 SO_4$	303 F g <sup>-1</sup> @ 2 mV s <sup>-1</sup>	34% at 500 mV s <sup>-1</sup>	[S3]
Pure Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/LiF	0.5 - 1.5 μm	1M H <sub>2</sub> SO <sub>4</sub>	245 F g <sup>-1</sup> @ 2 mV s <sup>-1</sup>	~83% at 100 mV s <sup>-1</sup>	[S4]
Pure Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/LiF	~1 µm	$3M H_2 SO_4$	290 F g <sup>-1</sup> @ 2 mV s <sup>-1</sup>	69% at 1000 mV s <sup>-1</sup>	[85]
Pure Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/LiF	~200-300 nm	$3M H_2 SO_4$	~260 F g <sup>-1</sup> @ 10 mV s <sup>-1</sup>	~60% at 1000 mV s <sup>-1</sup>	[S6]
Pristine Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	HCl/HF	/	1M H <sub>2</sub> SO <sub>4</sub>	~300 F g <sup>-1</sup> @ 5 mV s <sup>-1</sup>	~43.3% at 1000 mV s <sup>-1</sup>	[S7]
$O-Ti_3C_2T_x-3$	OAIC	1.62 μm	$3M H_2 SO_4$	352 F g <sup>-1</sup> @ 2 mV s <sup>-1</sup>	74.7% at 1000 mV s <sup>-1</sup>	This work

[a]. Rate performance was collected by reported data or calcultated according to gravimetric capacitance at the indicated scan rate compared to the values in column 5.

## **Supplementary References**

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